

FEATURES

Low offset voltage: 75 μV maximum
Low offset voltage drift: 1.0 $\mu\text{V}/^\circ\text{C}$ maximum
Very low bias current
25°C: 150 pA maximum
–40°C to +85°C: 300 pA maximum
Very high open-loop gain: 2000 V/mV minimum
Low supply current (per amplifier): 625 μA maximum
Operates from $\pm 2\text{ V}$ to $\pm 20\text{ V}$ supplies
High common-mode rejection: 114 dB minimum

APPLICATIONS

Strain gage and bridge amplifiers
 High stability thermocouple amplifiers
 Instrumentation amplifiers
 Photocurrent monitors
 High gain linearity amplifiers
 Long-term integrators/filters
 Sample-and-hold amplifiers
 Peak detectors
 Logarithmic amplifiers
 Battery-powered systems

GENERAL DESCRIPTION

The OP497 is a quad op amp with precision performance in the space-saving, industry standard 16-lead SOIC package. Its combination of exceptional precision with low power and extremely low input bias current makes the quad OP497 useful in a wide variety of applications.

Precision performance of the OP497 includes very low offset ($<50\text{ }\mu\text{V}$) and low drift ($<0.5\text{ }\mu\text{V}/^\circ\text{C}$). Open-loop gain exceeds 2000 V/mV ensuring high linearity in every application. Errors due to common-mode signals are eliminated by its common-mode rejection of $>120\text{ dB}$. The OP497 has a power supply rejection of $>120\text{ dB}$ which minimizes offset voltage changes experienced in battery-powered systems. The supply current of the OP497 is $<625\text{ }\mu\text{A}$ per amplifier, and it can operate with supply voltages as low as $\pm 2\text{ V}$.

The OP497 uses a superbeta input stage with bias current cancellation to maintain picoamp bias currents at all temperatures. This is in contrast to FET input op amps whose bias currents start in the picoamp range at 25°C but double for every 10°C rise in temperature to reach the nanoamp range above 85°C. The input bias current of the OP497 is $<100\text{ pA}$ at 25°C.

PIN CONNECTIONS

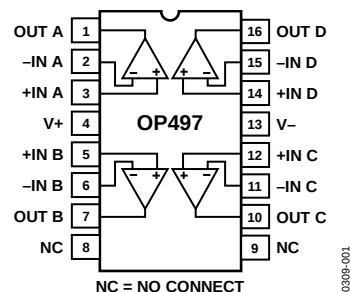


Figure 1. 16-Lead Wide Body SOIC (RW-16)

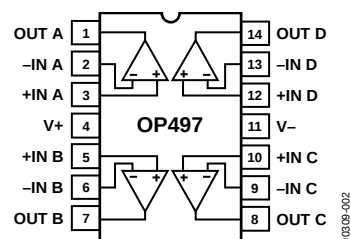


Figure 2. 14-Lead PDIP (N-14)

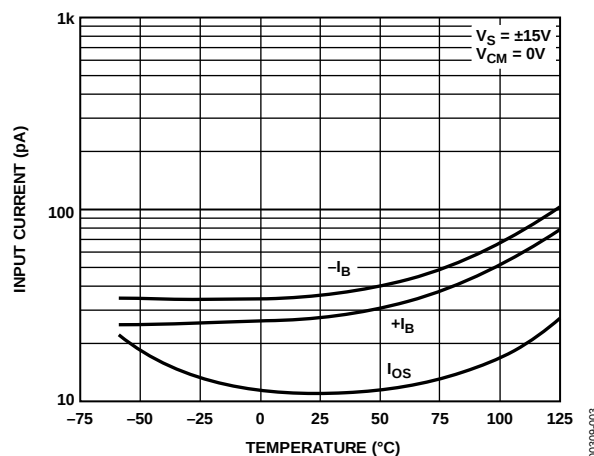


Figure 3. Input Bias, Offset Current vs. Temperature

Combining precision, low power, and low bias current, the OP497 is ideal for a number of applications, including instrumentation amplifiers, log amplifiers, photodiode preamplifiers, and long-term integrators. For a single device, see the [OP97](#) data sheet, and for a dual device, see the [OP297](#) data sheet.

Rev. E

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REVISION HISTORY

2/09—Rev. D to Rev. E

Deleted 14-Lead CERDIP.....	Throughout
Changes to Features Section and General Description	
Section.....	1
Delete Military Processed Devices Text, SMD Part Number,	
ADI Part Number Table, and Dice Characteristics Figure	3
Changes to Table 1.....	3
Changes to Absolute Maximum Ratings Section	4
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Deleted OP497 Spice Macro-Model Section.....	10
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Changes to Open-Loop Gain Linearity Section and	
Figure 35	11
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11/01—Rev. C to Rev. D

Edits to Pin Connection Headings.....	1
Deleted Wafer Test Limits	3
Edits to Absolute Maximum Ratings	5
Edits to Outline Dimensions.....	16
Edits to Ordering Guide	17

SPECIFICATIONS

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, unless otherwise noted.

Table 1.

Parameter	Symbol	Condition	F Grade			G Grade			Unit
			Min	Typ	Max	Min	Typ	Max	
INPUT CHARACTERISTICS									
Offset Voltage	V _{OS}		40	75		80	150		μV
		−40°C ≤ +85°C	70	150		120	250		μV
Average Input Offset Voltage Drift	TCV _{OS}	T _{MIN} − T _{MAX}	0.4	1.0		0.6	1.5		μV/°C
Long-Term Input Offset Voltage Stability			0.1			0.1			μV/Month
Input Bias Current	I _B	V _{CM} = 0 V	40	150		60	200		pA
		−40° ≤ T _A ≤ +85°C	60	200		80	300		pA
Average Input Bias Current Drift	TC _{IB}	−40° ≤ T _A ≤ +85°C	0.3			0.3			pA/°C
Input Offset Current	I _{OS}	V _{CM} = 0 V	30	150		50	200		pA
		−40° ≤ T _A ≤ +85°C	50	200		80	300		pA
Average Input Offset Current Drift	Tc _{Ios}		0.3			0.4			pA/°C
Input Voltage Range ¹	IVR		±13	±14		±13	±14		V
		T _{MIN} − T _{MAX}	±13	±13.5		±13	±13.5		V
Common-Mode Rejection	CMR	V _{CM} = ±13 V	114	135		114	135		dB
		T _{MIN} − T _{MAX}	108	120		108	120		dB
Large Signal Voltage Gain	A _{VO}	V _O = ±10 V, R _L = 2 kΩ	1500	4000		1200	4000		V/mV
		−40° ≤ T _A ≤ +85°C	800	2000		800	2000		V/mV
Input Resistance Differential Mode	R _{IN}			30			30		MΩ
Input Resistance Common Mode	R _{INCM}			500			500		GΩ
Input Capacitance	C _{IN}			3			3		pF
OUTPUT CHARACTERISTICS									
Output Voltage Swing	V _O	R _L = 2 kΩ	±13	±13.7		±13	±13.7		V
		R _L = 10 kΩ, T _{MIN} − T _{MAX}	±13	±14		±13	±14		V
		R _L = 10 kΩ	±13	±13.5		±13	±13.5		V
Short Circuit	I _{SC}			±25			±25		mA
POWER SUPPLY									
Power Supply Rejection Ratio	PSRR	V _S = ±2 V to ±20 V	114	135		114	135		dB
		V _S = ±2.5 V to ±20 V, T _{MIN} − T _{MAX}	108	120		108	120		dB
Supply Current (per Amplifier)	I _{SY}	No load		525	625		525	625	μA
		T _{MIN} − T _{MAX}		580	750	580	750		μA
Supply Voltage Range	V _S	Operating range	±2		±20	±2		±20	V
		T _{MIN} − T _{MAX}	±2.5		±20	±2.5		±20	V
DYNAMIC PERFORMANCE									
Slew Rate	SR		0.05	0.15		0.05	0.15		V/μs
Gain Bandwidth Product	GBW			500			500		kHz
Channel Separation	CS	V _O = 20 V p-p, f _o = 10 Hz		150			150		dB
NOISE PERFORMANCE									
Voltage Noise	e _n p-p	0.1 Hz to 10 Hz		0.3			0.3		μV/p-p
Voltage Noise Density	e _n	e _n = 10 Hz		17			17		nV/√Hz
		e _n = 1 kHz		15			15		nV/√Hz
Current Noise Density	i _n	i _n = 10 Hz		20			20		fA/√Hz

¹ Guaranteed by CMR test.

ABSOLUTE MAXIMUM RATINGS

Absolute maximum ratings apply to packaged parts.

Table 2.

Parameter	Rating
Supply Voltage	±20 V
Input Voltage ¹	20 V
Differential Input Voltage ¹	40 V
Output Short-Circuit Duration	Indefinite
Storage Temperature Range	–65°C to +150°C
Operating Temperature Range	–40°C to +85°C
Junction Temperature Range	–65°C to +150°C
Lead Temperature (Soldering, 60 sec)	300°C

¹For supply voltages less than ±20 V, the absolute maximum input voltage is equal to the supply voltage.

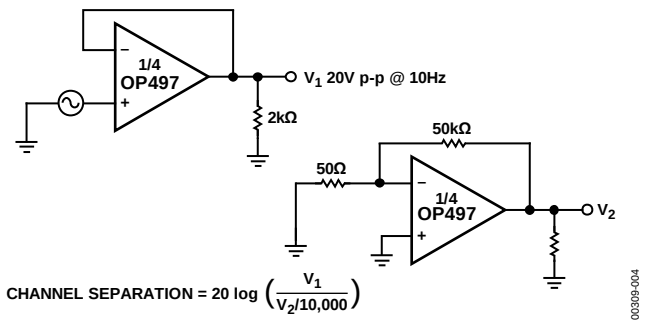
Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case mounting conditions, that is, θ_{JA} is specified for a device in socket for the PDIP package, and θ_{JA} is specified for a device soldered to the printed circuit board (PCB) for the SOIC package.

Table 3.

Package Type	θ_{JA}	θ_{JC}	Unit
14-Lead PDIP (N-14)	76	33	°C/W
16-Lead SOIC (RW-16)	92	23	°C/W



ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS

$T_A = 25^\circ\text{C}$, $V_S = \pm 15\text{ V}$, unless otherwise noted.

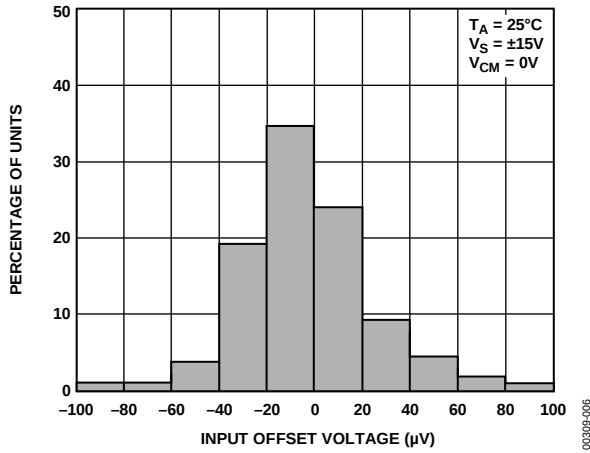


Figure 5. Typical Distribution of Input Offset Voltage

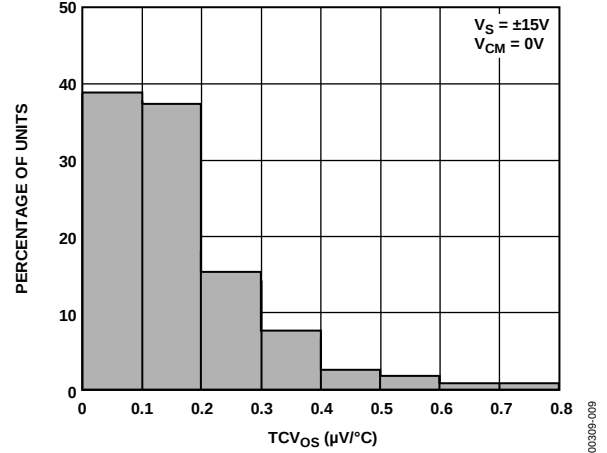


Figure 8. Typical Distribution of TCV_{OS}

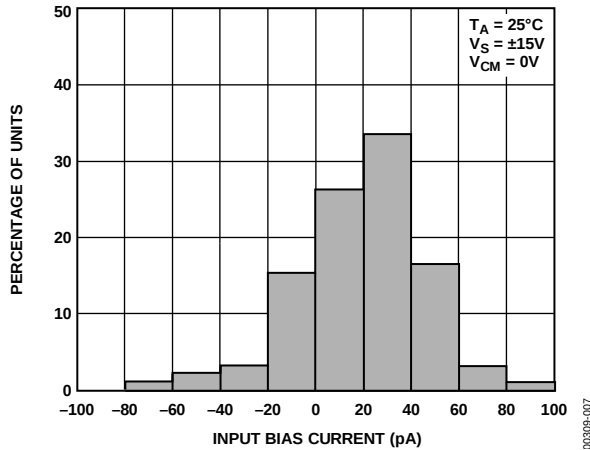


Figure 6. Typical Distribution of Input Bias Current

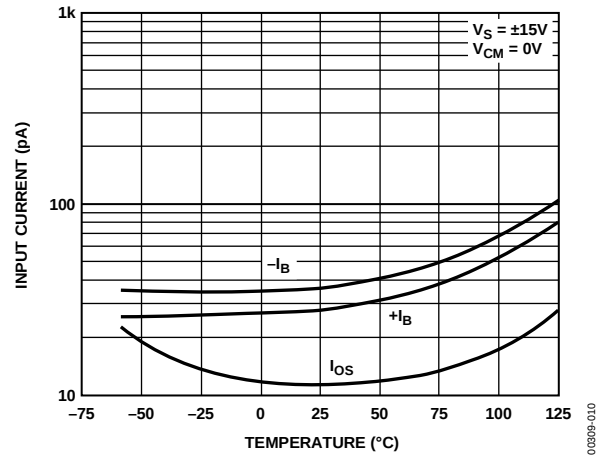


Figure 9. Input Bias, Offset Current vs. Temperature

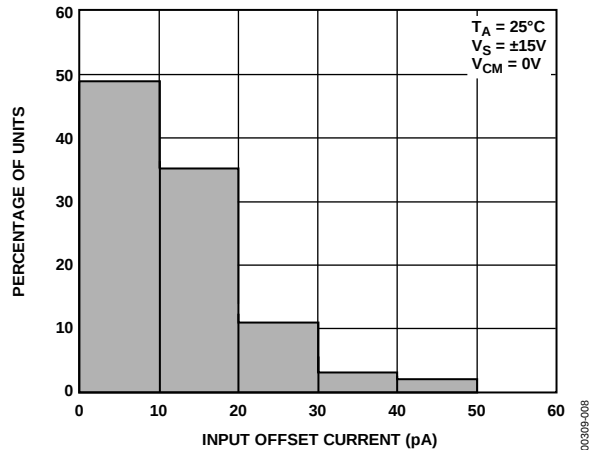


Figure 7. Typical Distribution of Input Offset Current

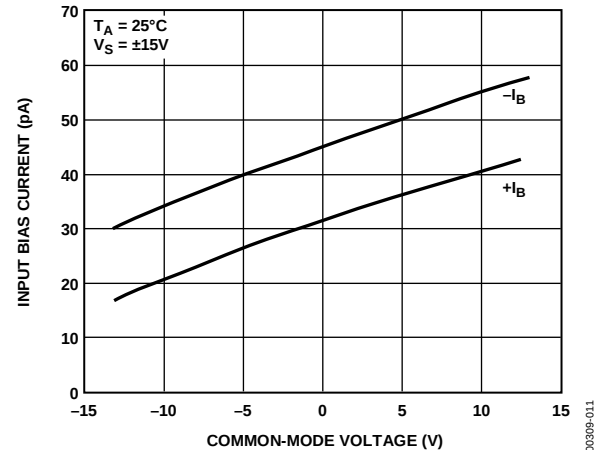


Figure 10. Input Bias Current vs. Common-Mode Voltage

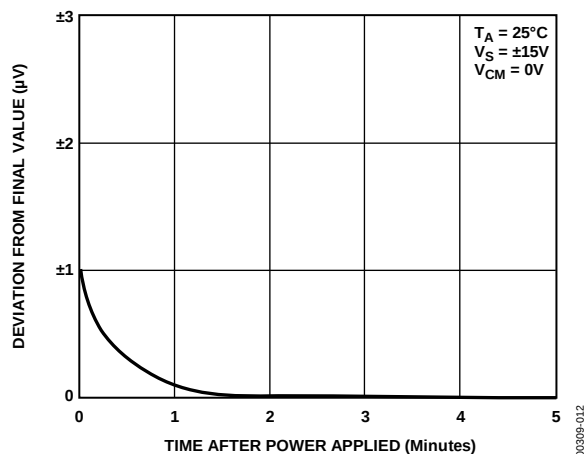


Figure 11. Input Offset Voltage Warm-Up Drift

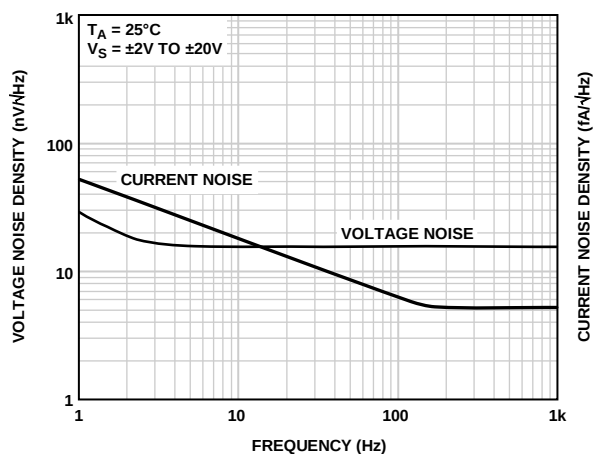


Figure 14. Voltage Noise Density vs. Frequency

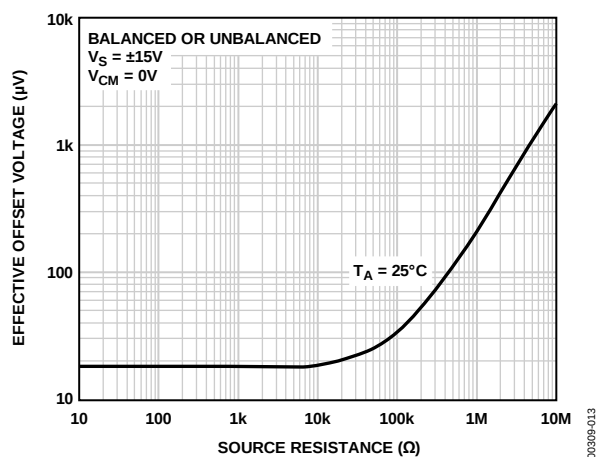


Figure 12. Effective Offset Voltage vs. Source Resistance

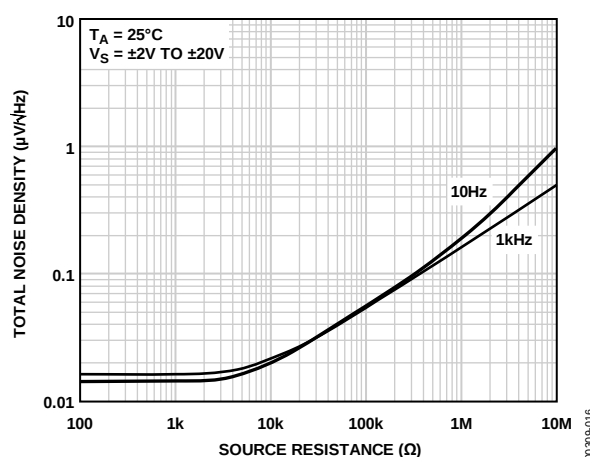


Figure 15. Total Noise Density vs. Source Resistance

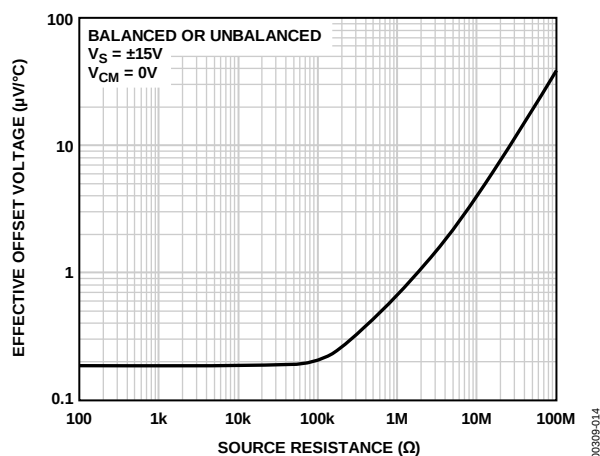


Figure 13. Effective TCV_{05} vs. Source Resistance

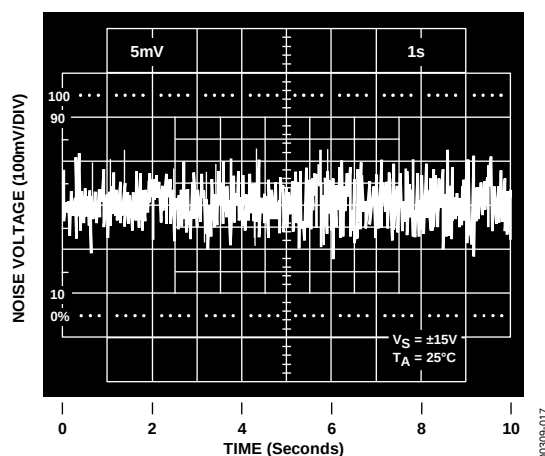


Figure 16. 0.1 Hz to 10 Hz Noise Voltage

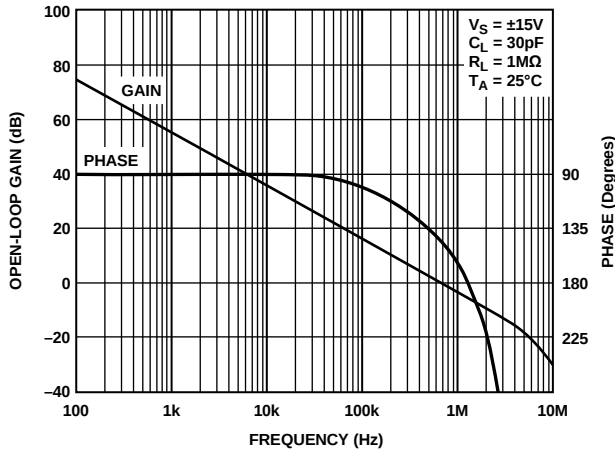


Figure 17. Open-Loop Gain and Phase vs. Frequency

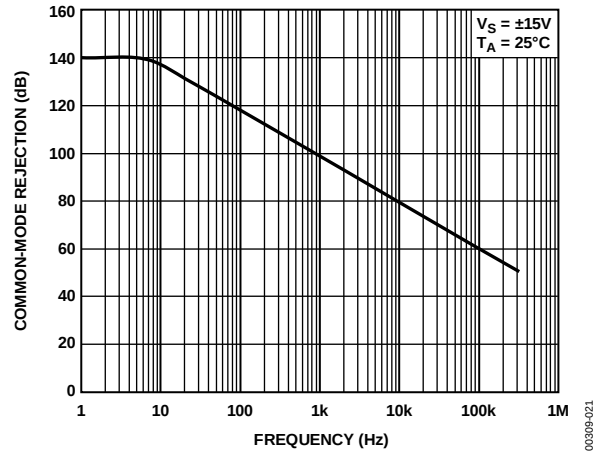


Figure 20. Common-Mode Rejection vs. Frequency

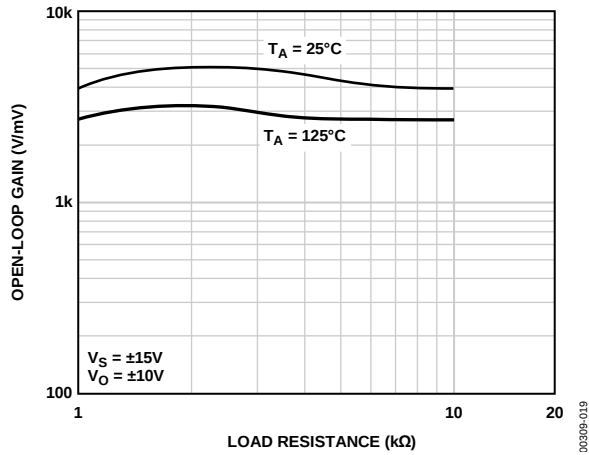


Figure 18. Open-Loop Gain vs. Load Resistance

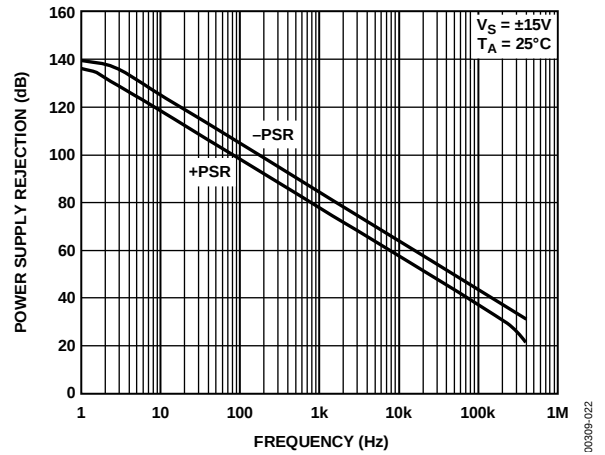


Figure 21. Power Supply Rejection vs. Frequency

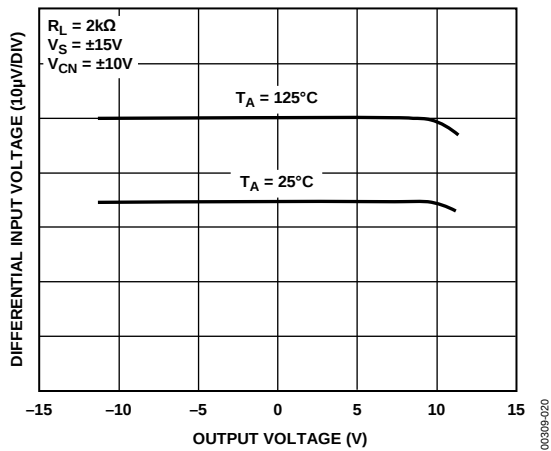


Figure 19. Open-Loop Gain Linearity

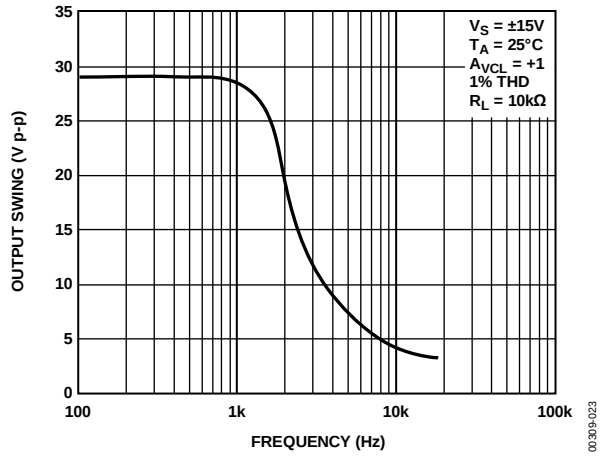


Figure 22. Maximum Output Swing vs. Frequency

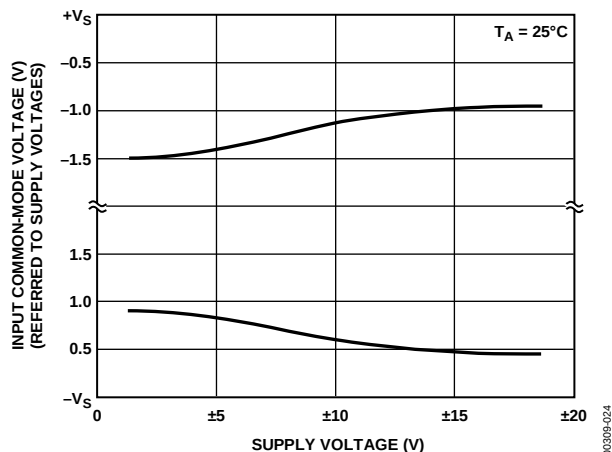


Figure 23. Input Common-Mode Voltage Range vs. Supply Voltage

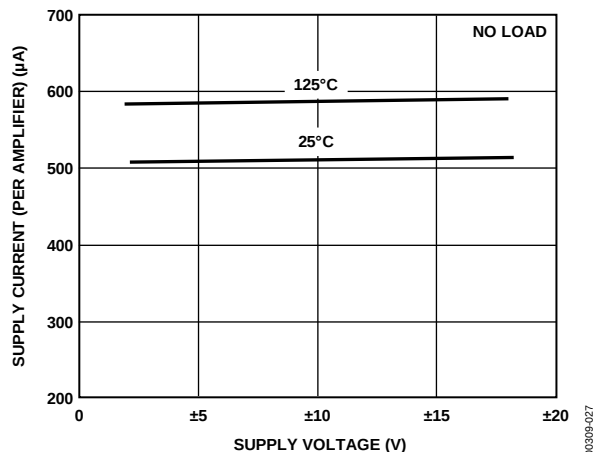


Figure 26. Supply Current (per Amplifier) vs. Supply Voltage

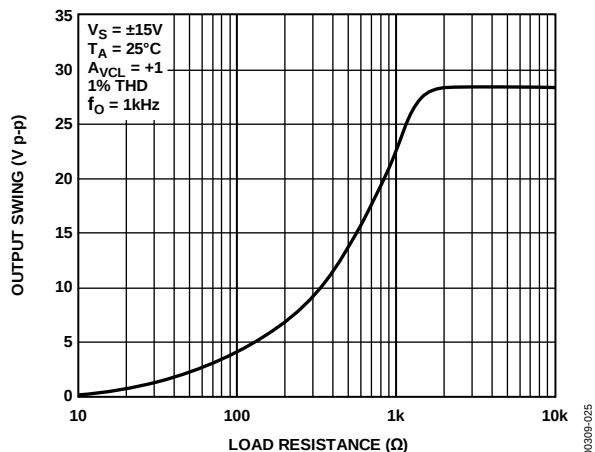


Figure 24. Maximum Output Swing vs. Load Resistance

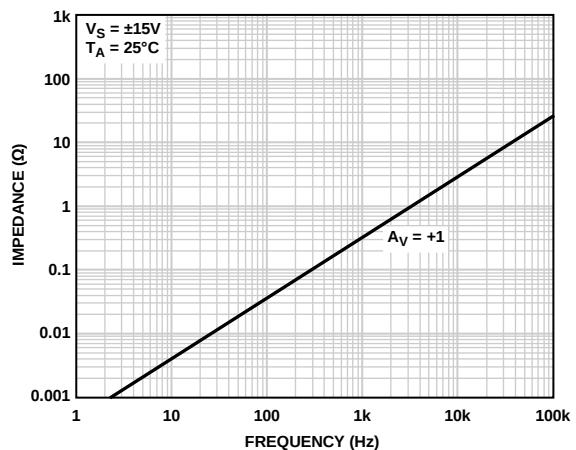


Figure 27. Closed-Loop Output Impedance vs. Frequency

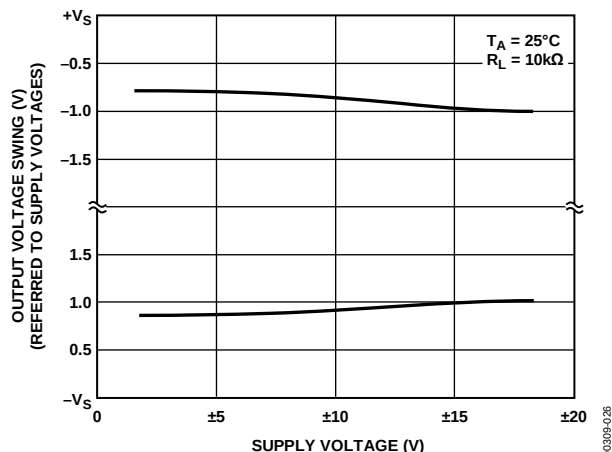


Figure 25. Output Voltage Swing vs. Supply Voltage

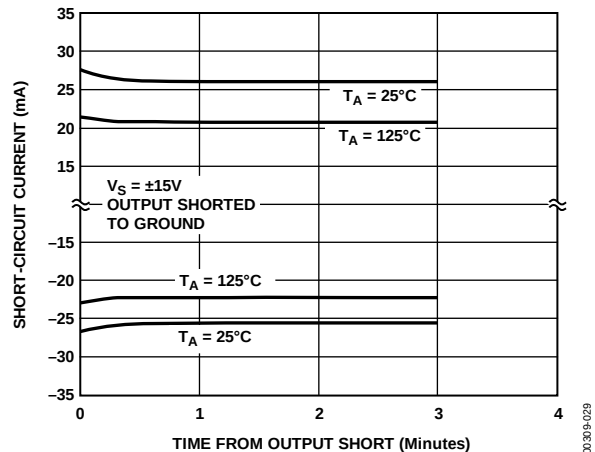


Figure 28. Short-Circuit Current vs. Time at Various Temperatures

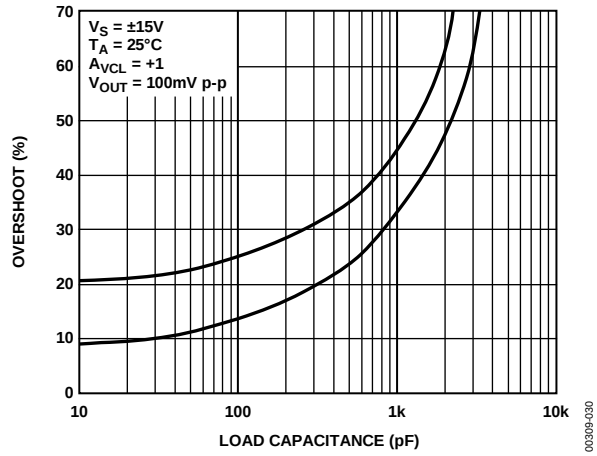


Figure 29. Small-Signal Overshoot vs. Load Capacitance

APPLICATIONS INFORMATION

Extremely low bias current makes the OP497 attractive for use in sample-and-hold amplifiers, peak detectors, and log amplifiers that must operate over a wide temperature range. Balancing input resistances is not necessary with the OP497. High source resistance, even when unbalanced, only minimally degrades the offset voltage and TCV_{OS} .

The input pins of the OP497 are protected against large differential voltage by back-to-back diodes and current-limiting resistors. Common-mode voltages at the inputs are not restricted and may vary over the full range of the supply voltages used.

The OP497 requires very little operating headroom about the supply rails and is specified for operation with supplies as low as ± 2 V. Typically, the common-mode range extends to within 1 V of either rail. When using a 10 k Ω load, the output typically swings to within 1 V of the rails.

AC PERFORMANCE

The ac characteristics of the OP497 are highly stable over its full operating temperature range. Figure 30 shows the unity-gain small signal response. Extremely tolerant of capacitive loading on the output, the OP497 displays excellent response even with 1000 pF loads (see Figure 31).

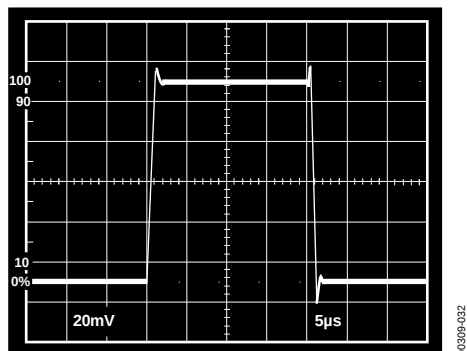


Figure 30. Small Signal Transient Response ($C_{LOAD} = 100$ pF, $A_{VCL} = +1$)

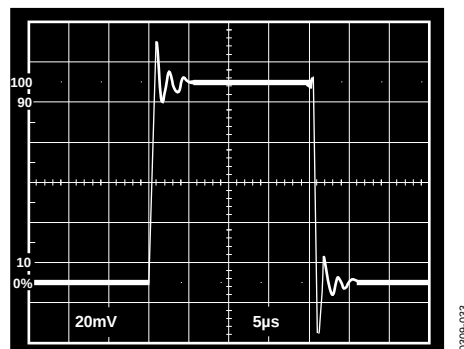


Figure 31. Small Signal Transient Response ($C_{LOAD} = 1000$ pF, $A_{VCL} = +1$)

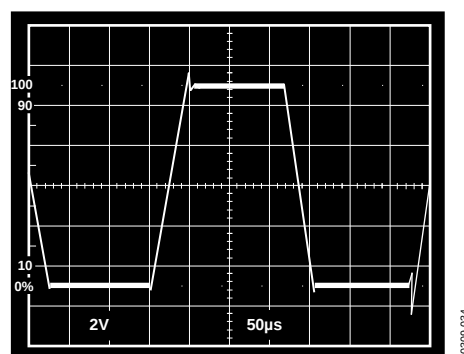


Figure 32. Large Signal Transient Response ($A_{VCL} = +1$)

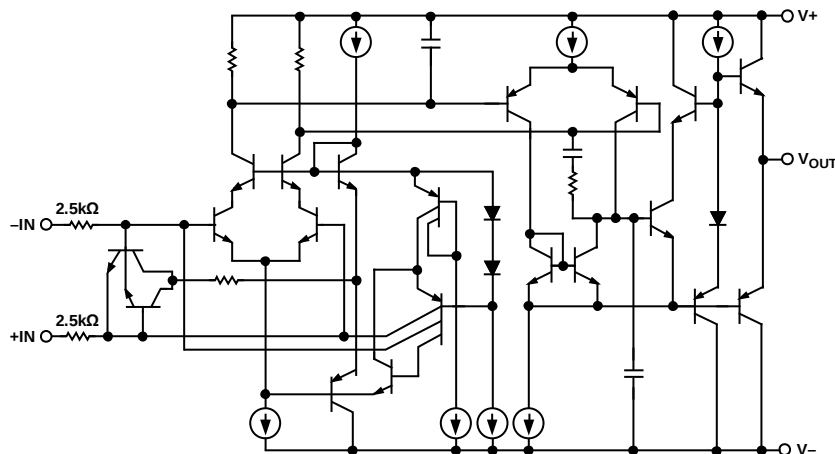


Figure 33. Simplified Schematic Showing One Amplifier

GUARDING AND SHIELDING

To maintain the extremely high input impedances of the OP497, care must be taken in circuit board layout and manufacturing. Board surfaces must be kept scrupulously clean and free of moisture. Conformal coating is recommended to provide a humidity barrier. Even a clean PCB can have 100 pA of leakage currents between adjacent traces; therefore, use guard rings around the inputs. Guard traces are operated at a voltage close to that on the inputs, as shown in Figure 34, so that leakage currents become minimal. In noninverting applications, connect the guard ring to the common-mode voltage at the inverting input. In inverting applications, both inputs remain at ground; therefore, the guard trace should be grounded. Place guard traces on both sides of the circuit board.

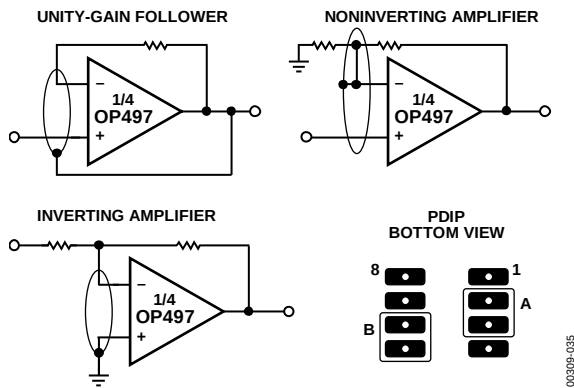


Figure 34. Guard Ring Layout and Connections

OPEN-LOOP GAIN LINEARITY

The OP497 has both an extremely high gain of 2000 V/mV typical and constant gain linearity. This enhances the precision of the OP497 and provides for very high accuracy in high closed-loop gain applications. Figure 35 illustrates the typical open-loop gain linearity of the OP497.

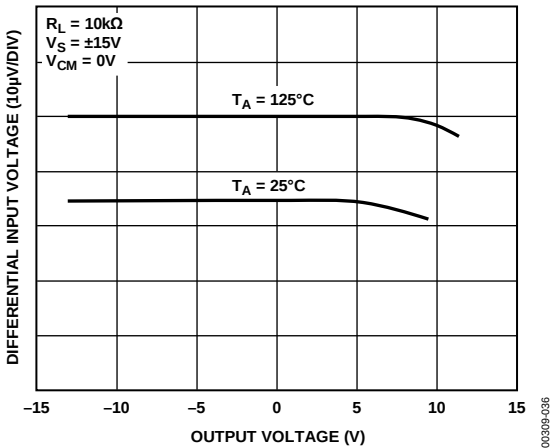
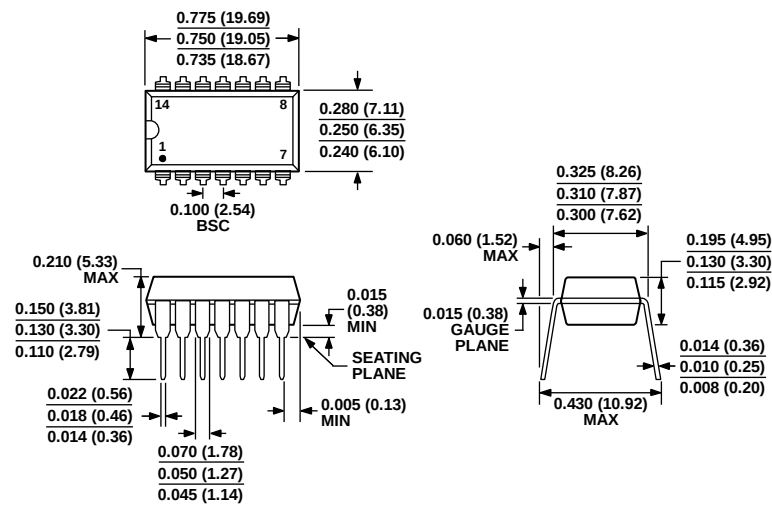


Figure 35. Open-Loop Gain Linearity

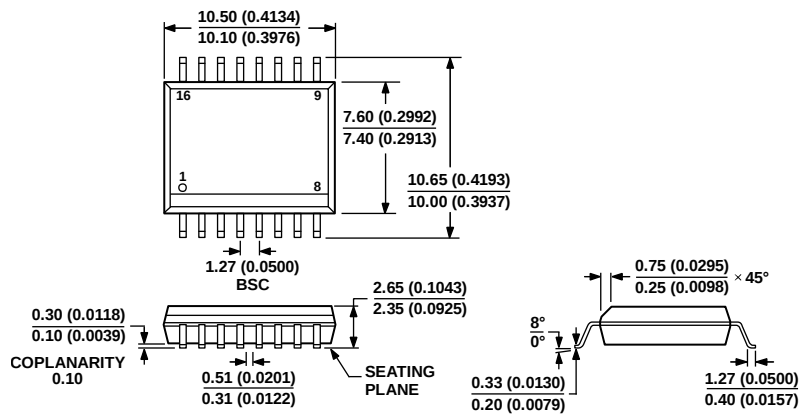
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-001
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 42. 14-Lead Plastic Dual In-Line Package [PDIP]
Narrow Body
(N-14)

Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-013-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 43. 16-Lead Standard Small Outline Package [SOIC_W]
Wide Body
(RW-16)

Dimensions shown in millimeters and (inches)

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
OP497FP	–40°C to +85°C	14-Lead Plastic Dual In-Line Package [PDIP]	N-14
OP497FPZ ¹	–40°C to +85°C	14-Lead Plastic Dual In-Line Package [PDIP]	N-14
OP497GP	–40°C to +85°C	14-Lead Plastic Dual In-Line Package [PDIP]	N-14
OP497GPZ ¹	–40°C to +85°C	14-Lead Plastic Dual In-Line Package [PDIP]	N-14
OP497FS	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16
OP497FS-REEL	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16
OP497FSZ ¹	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16
OP497FSZ-REEL	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16
OP497GS	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16
OP497GS-REEL	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16
OP497GSZ ¹	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16
OP497GSZ-REEL ¹	–40°C to +85°C	16-Lead Standard Small Outline Package [SOIC_W]	RW-16

¹ Z = RoHS Compliant Part.

OP497

NOTES



**Стандарт
Электрон
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

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